



DECODING IC COMPATIBLE TO QUALCOMM QUICK CHARGE 2.0 PROTOCOL

Description

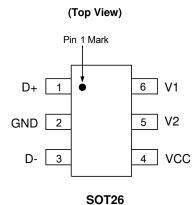
The AP4370 is a decoding IC compatible to Qualcomm High Voltage Dedicated Charging Port (HVDCP) Quick Charge (QC) 2.0 protocol. It decodes the different combinations of D+/D- signals, generated by the portable device, into the related configurations of V1/V2, which can be used to change either voltage reference or voltage feedback divider resister for the controller IC to make the further constant voltage/constant current control. The AP4370 has over voltage discharge feature to accelerate output voltage decline transition. The AP4370 automatically provides 5V output configuration for the connected portable device that is not compatible to Qualcomm QC 2.0 protocol.

The AP4370 is packaged in SOT26 package.

Features

- Compatible to Qualcomm HVDCP Quick Charge 2.0 Protocol Class A: 5V/9V/12V
- Ultra Low Static Current: 80µA at 5V V_{CC}
- Wide V_{CC} Supply Voltage: 4.5V to 15V
- Over Voltage Discharge Feature to Accelerate Output Voltage Decline Transition
- Small Profile: SOT26 SMD Package in Accordance with Level 3 of IPC/JEDEC J-STD-033A
- Totally Lead-free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



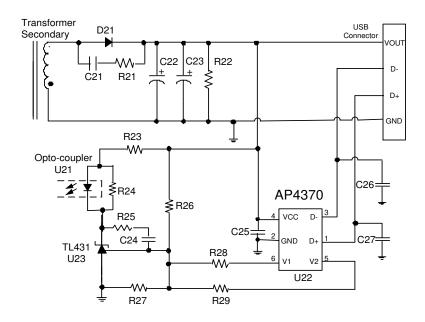
Applications

Chargers/ Adapters

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Typical Applications Circuit

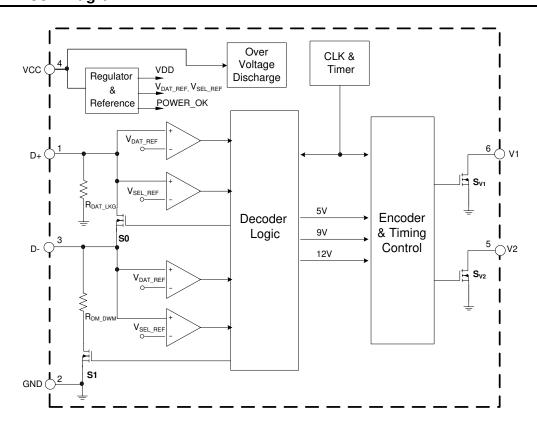




Pin Descriptions

Pin Number	Pin Name	Function		
1	D+	USB D+ Input		
2	GND	Ground Return		
3	D-	USB D- Input		
4	VCC	IC Supply Voltage, connected to a ceramic cap.		
5	V2	Decoder Output2, used as input of constant voltage/constant current controller		
6	V1	Decoder Output1, used as input of constant voltage/constant current controller		

Functional Block Diagram



Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Rating	Unit
Vcc	IC Supply Voltage	-0.3 to 25	V
V_{D+}/V_{D-}	USB Input Voltage	-0.3 to 7	V
V_{V1}/V_{V2}	Decoder Output Voltage	-0.3 to 7	V
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
T _{LEAD}	Lead Temperature (Soldering, 10 sec)	+300	°C
θυα	Thermal Resistance (Junction to Ambient)	200	°C/W
ESD	ESD (Human Body Model)	4000	V
E2D	ESD (Machine Model)	150	V

Note 4: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.



Electrical Characteristics ($V_{CC} = 5V$, $T_A = +25$ °C, unless otherwise specified.)

Symbol	Parameters	Conditions	Min	Тур	Max	Unit		
STARTUP AND UVLO SECTION								
V _{TH_ST}	Vcc Startup Threshold	-	3.4	3.8	4.2	V		
V _{OPR(MIN)}	Vcc Minimal Operating Voltage	-	3.2	3.6	4.0	V		
STANDBY CURRE	STANDBY CURRENT SECTION							
I _{CC}	Operating Current	-	_	80	120	μΑ		
QUICK CHARGE I	PROTOCOL SECTION		•	•				
V _{DAT_REF}	Data Detect Voltage	-	0.25	0.325	0.40	V		
V _{SEL_REF}	Output Voltage Selection Reference	-	1.8	2.0	2.2	V		
R _{DAT_LKG}	Data Line Leakage Resistance	-	300	500	800	kΩ		
R _{DCP_DAT}	D+ to D- Resistance during DCP Mode	D+ is supplied with 0.6V	_	20	40	Ω		
R _{DM_DWM}	D- Pull-down Resistance	-	14.25	19.53	24.80	kΩ		
tglitch_bc_done	D+ High Glitch Filter Time	-	1	1.25	1.5	s		
tGLITCH_DM_LOW	D- Low Glitch Filter Time	Note 5	1	2.5	-	ms		
tglitch_v_change	Output Voltage Glitch Filter Time	-	20	40	60	ms		
t _{D+_D} short	D+ D- HVDCP Short Time	-	-	10	20	ms		
C _{DCP_PWR}	D+/- Equivalent Capacitance	Note 5	_	-	1	nF		
$V_{OTG_SESS_VLD}$	OTG Session Valid Voltage	-	0.8	-	4.0	V		
OUTPUT SECTION	OUTPUT SECTION							
R _{V1_ON}	V1 Switch Turn-on Resistance	-	-	15	25	Ω		
R _{V2_ON}	V2 Switch Turn-on Resistance	-	-	10	18	Ω		
R _{V1/V2_OFF}	V1/V2 Switch Turn-off Resistance	-	High-Z		-			
OVER VOLTAGE DISCHARGE SECTION								
V_{OVD5V}	Over Voltage Discharge Trigger Point for 5V Output	_	5.96	6.15	6.33	V		
V _{OVD9V}	Over Voltage Discharge Trigger Point for 9V Output	-	10.58	10.91	11.24	V		
Ratio of Target Voltage for Discharge Finish to OVD Trigger Point		-	-	0.9	_	_		
I _{OVD}	Over Voltage Discharge Current	-	65	85	110	mA		
tovp	Over Voltage Discharge Duration	-	-	120	-	ms		

Note 5: Guaranteed by design.



Operation Principle Description

Overall Introduction

The figure on page 1 is the typical application circuit of AP4370, which follows Qualcomm HVDC Quick Charge 2.0 Protocol to decode the different combinations of D+/D- signals, generated by the portable device, into the related configurations of V1/V2 for the controller IC to make the further constant voltage/constant current control. The AP4370 automatically provides 5V output configuration for the connected portable device that is not compatible to QC 2.0 protocol. When the portable device requests a lower output voltage, the AP4370 will have over voltage discharge function operate until the output voltage reaches V_{OVDXV} * k_{DIS} or the time duration is over tovD.

Quick Charge 2.0 Protocol Operation

The switches of S1, S_{V1} and S_{V2} (shown in Functional Block Diagram on page 2) will be kept turn-off during the start-up phase, and the default V1/V2 configuration ensures that the charger/adapter is regulated into 5V output voltage. S0 switch will be turned on to short D+ to D- at start-up voltage within $V_{OTG_SESS_VLD}$ (0.8V to 4.0V). If AP4370 finds D+ voltage is between V_{DAT_REF} (0.325V, typical) and V_{SEL_REF} (2.0V, typical) lasting for $t_{GLITCH_BC_DONE}$, it will turn off S0 to have D+ / D- open, and turn on S1 to have D- connected to GND via $t_{GLITCH_DM_DMM}$ (19.53k $t_{GLITCH_DM_LOW}$ (1ms, min) to successfully complete Qualcomm QC 2.0 protocol handshake. After that, AP4370 can respond to the voltage request made by the portable device via D+/D- data lines. If AP4370 detects that D+/D- keeps voltage unchanged for a glitch filter period of $t_{GLITCH_V_CHANGE}$ (40ms, typical), it will follow the voltage decoding table below to configure V1/V2 by turning on/off $t_{GLITCH_V_CHANGE}$ (40ms, typical), after the portable device is removed from USB connector, AP4370 will have D+ shorted to D- within $t_{D+D-SHORT}$ (20ms, max), configure V1/V2 to 5V output, and is ready for next handshake.

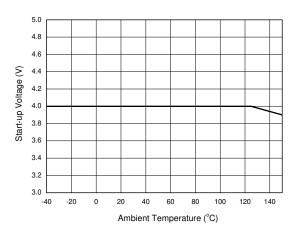
Decoder	D+ (V)	D- (V)	V1 Switch(S _{V1}) Status	V2 Switch(S _{V2}) Status	HVDCP Voltage (V)
	0.6	0.6	Turn-on	Turn-on	12
Quick Charge 2.0 Protocol Class A: 5V, 9V, 12V	3.3	0.6	Turn-on Turn-off 9		
01000711 007, 007, 120	0.6	3.3	Keep	Keep Present V1/V2 Status Unch	
	3.3	3.3	Keep Present V1/V2 Status Unchanged		nchanged
	0.6 or 3.3	GND	Turn-off	Turn-off	5
	GND	0.6 or 3.3 or GND	Turn-off	Turn-off	5, AP4370 Protocol Handshake Reset

Table 1. D+/D- Voltage Decoder

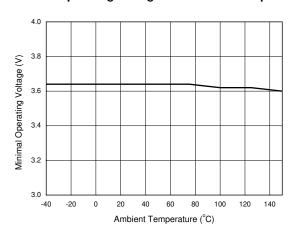


Performance Characteristics

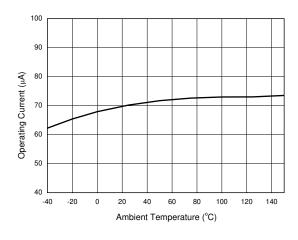
Startup Voltage vs. Ambient Temperature



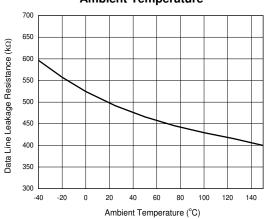
Minimal Operating Voltage vs. Ambient Temperature



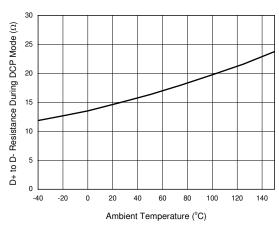
Operating Current vs. Ambient Temperature



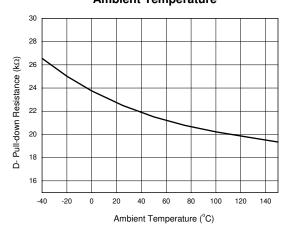
Data Line Leakage Resistance vs.
Ambient Temperature



D+ to D- Resistance During DCP Mode vs. Ambient Temperature



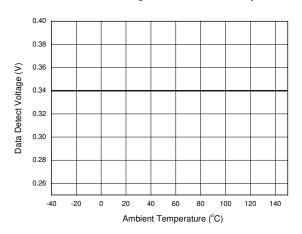
D- Pull-down Resistance vs.
Ambient Temperature



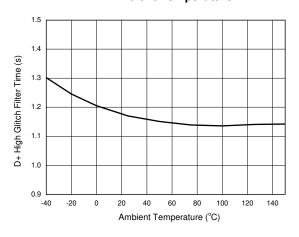


Performance Characteristics (Cont.)

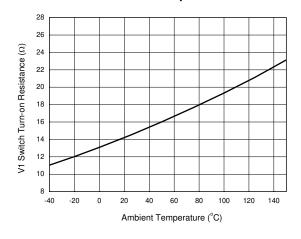
Data Detect Voltage vs. Ambient Temperature



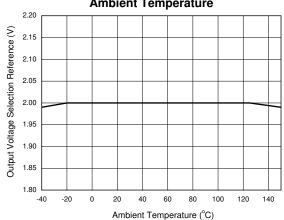
D+ High Glitch Filter Time vs. Ambient Temperature



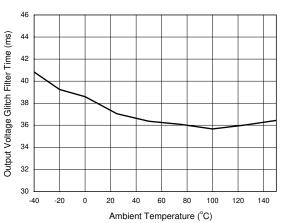
V1 Switch Turn-on Resistance vs. Ambient Temperature



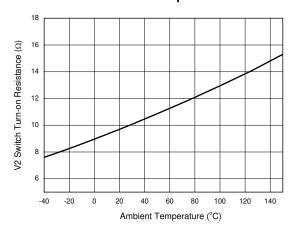
Output Voltage Selection Reference vs. Ambient Temperature



Output Voltage Glitch Filter Time vs. Ambient Temperature

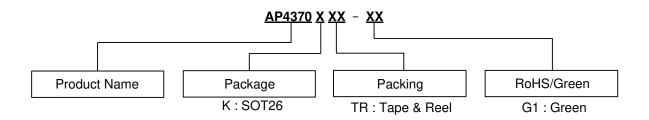


V2 Switch Turn-on Resistance vs. Ambient Temperature





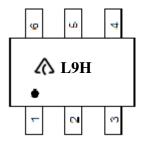
Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing	
SOT26	-40 to +85°C	AP4370KTR-G1	L9H	3000/Tape & Reel	

Marking Information

(Top View)

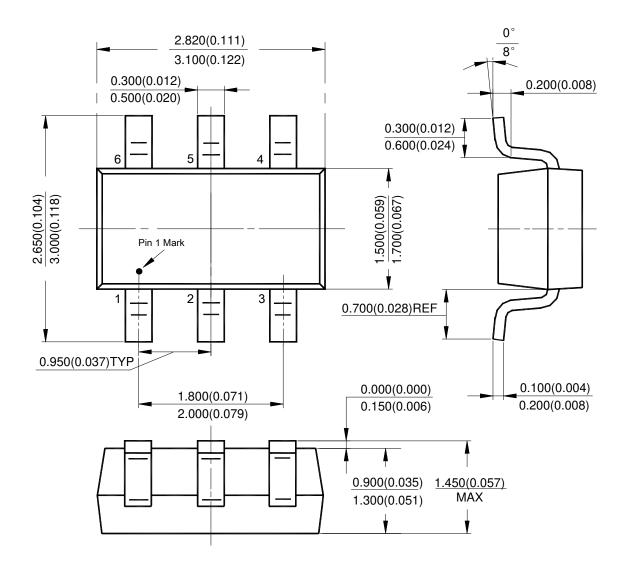


: Logo L9H: Marking ID



Package Outline Dimensions (All dimensions in mm(inch).)

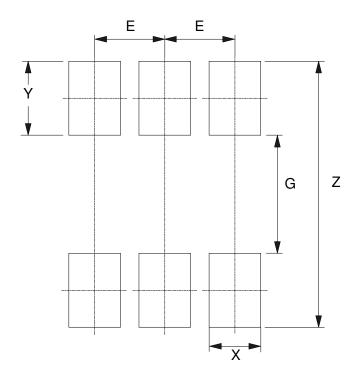
(1) Package Type: SOT26





Suggested Pad Layout

(1) Package Type: SOT26



Dimensions	Z (mm)/(inch)	G (mm)/(inch)	X Y (mm)/(inch) (mm)/(inch)		E (mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037



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